



MBR1080F THRU MBR10200F

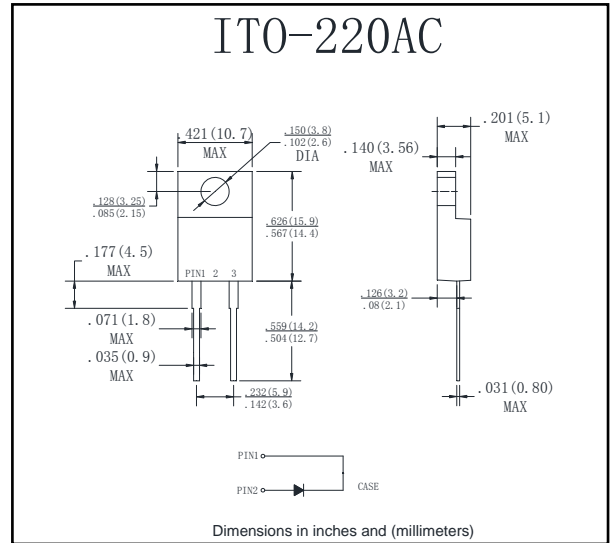
RoHS
COMPLIANT

肖特基二极管 SCHOTTKY Diodes

■特征 Features

- 耐正向浪涌电流能力高
High surge forward current capability
- 低功耗，大电流
Low Power loss, High efficiency
- I_o 10.0A
- V_{RRM} 80~200V

■外形尺寸和印记 Outline Dimensions and Mark



■用途 Applications

- 快速整流用
High speed switching

■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	MBR-F			
				1080	10100	10150	10200
反向重复峰值电压 Repetitive Peak Reverse Voltage	V_{RRM}	V		80	100	150	200
平均整流输出电流 Average Rectified Output Current	I_o	A	60Hz 正弦波，电阻负载， $T_a=25^\circ\text{C}$ 60Hz sine wave, R- load, $T_a=25^\circ\text{C}$	20			
正向（不重复）浪涌电流 Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz正弦波，一个周期， $T_a=25^\circ\text{C}$ 60Hz sine wave, 1 cycle, $T_a=25^\circ\text{C}$	150			
正向浪涌电流的平方对电流浪涌持续时间的积分值 Current Squared Time	I^2t	A^2s	$1\text{ms} \leq t < 8.3\text{ms}$ $T_j=25^\circ\text{C}$, 单个二极管 $1\text{ms} \leq t < 8.3\text{ms}$ $T_j=25^\circ\text{C}$, Rating of per diode	94			
贮存温度 Storage Temperature	T_{stg}	$^\circ\text{C}$		-55 ~ +150			
结温 Junction Temperature	T_j	$^\circ\text{C}$	在正向直流条件下，没有施加反向电压，通电 $\leq 1\text{h}$ （图示1）① IN DC Forward Mode-Forward Operations, without reverse bias, $t \leq 1\text{h}$ (Fig. 1)①	-55 ~ +150			

■电特性（ $T_a=25^\circ\text{C}$ 除非另有规定）

Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Condition	MBR-F			
				1080	10100	10150	10200
正向峰值电压 Peak Forward Voltage	V_{FM}	V	$I_{FM} = 10.0\text{A}$	0.85		0.95.	
反向峰值电流 Peak Reverse Current	I_{RRM1}	mA	$V_{RM} = V_{RRM}$	$T_a=25^\circ\text{C}$			
	I_{RRM2}			$T_a=125^\circ\text{C}$			
热阻 Thermal Resistance	$R_{\theta J-C}$	$^\circ\text{C}/\text{W}$	结和壳之间 Between junction and case	2.0			

■备注 NOTE

- ① Meets the requirement of IEC 61215 Ed. 2 bypass diode thermal test

■ 特性曲线 (典型) Characteristics(Typical)

图1: 正向电流降额曲线
FIG1: IF (AV) --Tc Derating

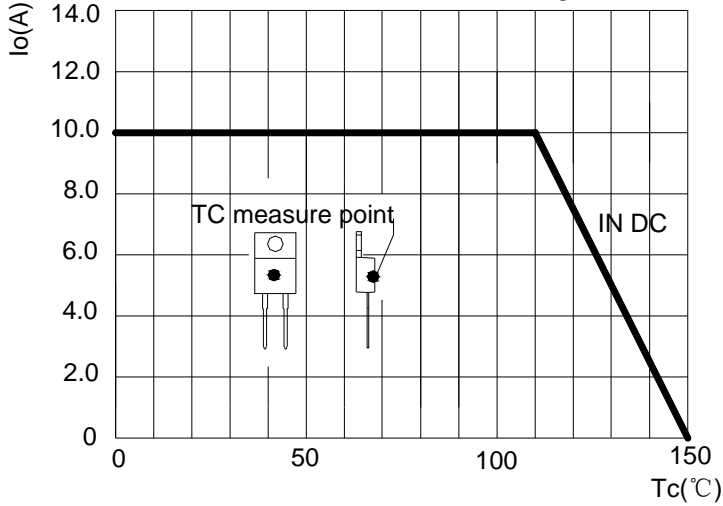


图2: 耐正向浪涌电流曲线
FIG2: Surge Forward Current Capadility

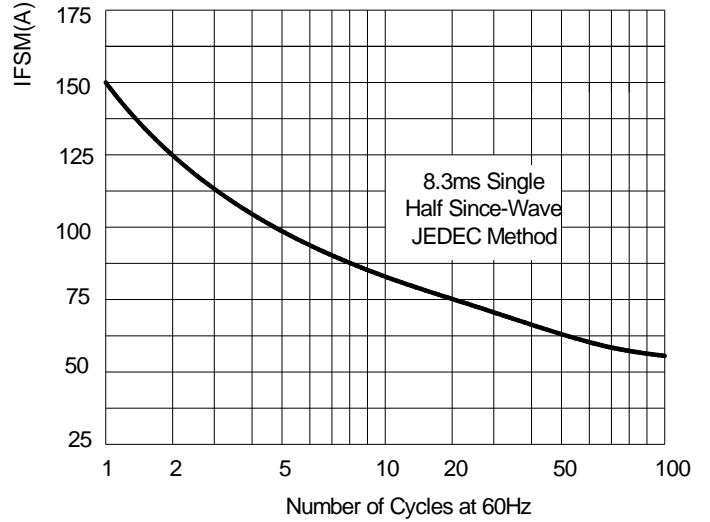


图3: 正向电压曲线
FIG3: Instantaneous Forward Voltage

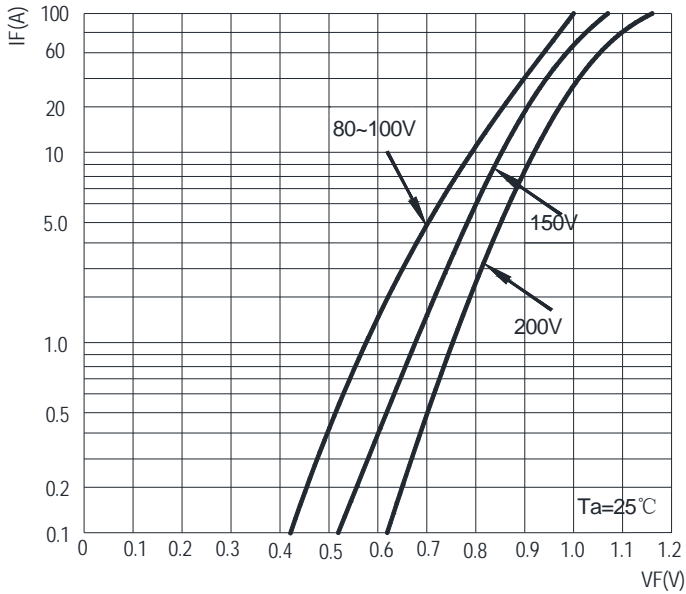
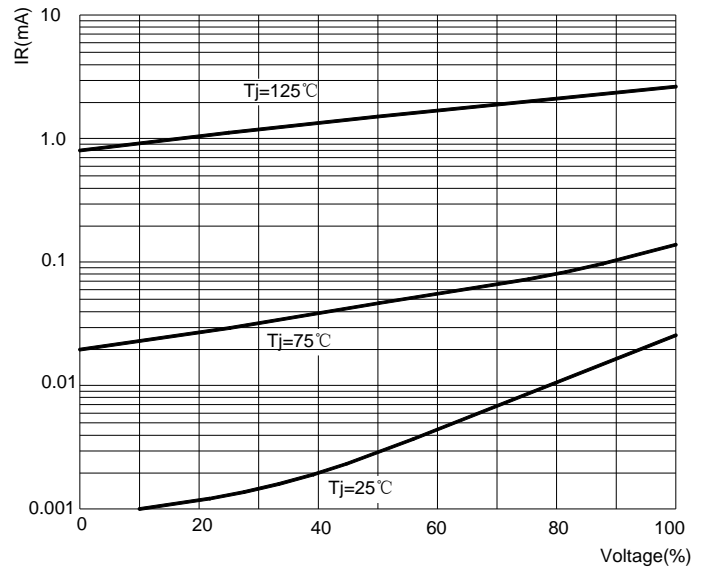


图4: 典型反向特性曲线
FIG.4: TYPICAL REVERSE CHARACTERISTICS



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